IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Chung-Hui Chen Examiner: Unknown

Group Art Unit: Unknown Serial No.: 10/784,705

Filed: February 23, 2004 Attorney Docket No.: N1280-00100

PROGRAMMABLE MOS DEVICE FORMED BY STRESSING For:

POLYCRYSTALLINE SILICON

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

This Information Disclosure Statement is being filed in connection with the patent application referenced above. The Examiner is requested to consider each of the references cited herein and forward an initialed copy of the enclosed PTO Form 1449 to the undersigned representative. This Statement is being filed:

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		Upon	n filing the application.						
contin	Within three months from the filing date of this application, which is not ontinued prosecution application.								
		Within three months from date of entry of the national stage for this application.							
		Before	e the mailing date of a first Office action on the merits for this application.						
contin	□ ued exa	Before the mailing date of a first Office action after the filing of a request for mination.							
	nce, ar mpanie	Before the mailing date of any of: (i) a Final Office Action, (ii) a Notice of and (iii) any other action that closes prosecution of this application. The Statement ed by:							
			A Statement pursuant to 37 C.F.R. §1.97(e) or						
			The fee set forth in 37 C.F.R. §1.17(p), believed to be						
			Before payment of the Issue Fee. The Statement is accompanied by:						
			A Statement pursuant to 37 C.F.R. §1.97(e) and						
			The fee set forth in 37 C.F.R. §1.17(p), believed to be						

I.	Provis	ion of Copies
enclos		A copy of each of the references listed on the attached Form PTO Form 1449 is with and forms a part hereof.
part he		A translation of References AA, AB and AC are enclosed herewith and form a
applica		A copy of the European Search Report from a corresponding or related EPO enclosed herewith.
applica		A copy of the International Search Report from a corresponding or related PCT enclosed herewith.
Applic submit	ation N	This application claims priority, pursuant to 35 U.S.C. §120, to prior U.S. to, filed References not submitted herewith were recited by the Office in the prior application(s).
II.	Fee	
	nis com	No fee is believed due in connection with filing of this Statement. However, in e or refund is due, the Commissioner is authorized to charge any fee associated munication or credit any overpayment to Deposit Account No. 04-1679 (N1280-
Statem		The fee in the amount \$ that is due in connection of filing of this spaid upon electronic filing of a corresponding Statement, which was made on sing the ePAVE software.
to be d	ue in co	The fee set forth in 37 C.F.R. §1.17(p), believed to be \$, is believed nnection of filing of this Statement.
		A check in the amount \$ is enclosed.
	X	The Commissioner is authorized to charge any other fee associated with this

Respectfully submitted,

Dated: 41 / 2014

Edward J. Lynch, Reg No. 24,422

Attorney For Applicant

DUANE MORRIS LLP

One Market Street, Spear Tower, Suite 2000

San Francisco, CA 94105-1104

(415) 371-2200 (Telephone)

(415) 371-2201 (Fax)

communication, or credit any overpayment, to Deposit Account No. 04-1679 (N1280-00100).

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OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS	OTHER PR	IOR ART		* * *					
Examiner Cite (Include name of author in CAPITAL LETTERS, Title of the Article (when appropriate)	Examiner								
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EXAMINER	DATE CONSIDERED

Ker, Ming-Dou et al., "COMPLEMENTARY-SCR ESD PROTECTION CIRCUIT WITH INTERDIGITATED FINGER-TYPE LAYOUT FOR INPUT PADS OF SUBMICRON

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Wu et al., A NEW ON-CHIP ESD PROTECTION CIRCUIT WITH DUAL PARASITIC

SCR STRUCTURES FOR CMOS VLSI, IEEE Journal of Solid-State Circuits, Vol. 27, No.

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.

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